A Simple and Efficient Procedure for Identifying the Compressing Stage in Two-Stage Amplifiers

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Abstract — We propose a fast and simple method to accurately determine the compressing stage in a two-stage amplifier system based on reverse intermodulation and hot S-parameter measurements. The method uses no specialized hardware and needs little reconfiguration, simplifying the measurements. We demonstrate its validity over a broad range of amplifiers designed in various semiconductor technologies. This method is a very useful tool in understanding or debugging amplifier designs.

Keywords — compression, intermodulation, reverse intermodulation, power amplifiers, nonlinearity

I. INTRODUCTION

Power amplifiers (PAs) for modern telecommunications and radar are often highly integrated multistage devices, which make them increasingly complex to design and debug. For example, a PA will not be able to deliver the designed power if the first stage compresses too early. Designers have to rely on limited measurements and their own experience to understand the root cause of such early compression in a PA or even just identifying the limiting stage, resulting in several costly design iterations before design tolerances are met [1]. Currently available debugging techniques either rely on sophisticated measurement equipment [2], [3], difficult time-domain measurements [4], idealized analysis [5], or placing measurement probes between the active stages, if possible at all.

In this paper we present a simple method for identifying the compressing stage in two-stage amplifiers based on an empirical relation used to estimate reverse intermodulation distortion (RIMD) from intermodulation distortion (IMD) measurements [6]. The proposed method is similar in nature and complexity to measuring hot S-parameters [7] and offers good insights into the behaviour of a two-stage PA while being simple and easy to implement without requiring expensive nonlinear VNAs.

In Section II we demonstrate the generality of our empirical RIMD estimator by providing a mathematical relation between IMD and RIMD using a general large-signal transistor model [8]. We show that the error between the RIMD estimator and measurement result can be used to determine the compressing stage in a two-stage PA. In Section III a complete measurement procedure is presented, including representative measurements of PAs implemented in several semiconductor technologies to verify the validity of the procedure. Finally, the conclusions are summarized in Section IV.

II. STAGE COMPRESSION IDENTIFICATION USING RIMD

A. RIMD Estimator Analysis

In our previous work [6] we examined the reverse intermodulation products generated when a PA is transmitting power at one frequency while reverse power, at a close frequency offset, is injected into its output. We showed how they relate to regular IMD products generated using the same power levels. We defined a simple dB-scale relation to estimate the strongest RIMD component, RIM31, from the measurement of the strongest IMD component, IM31, via general device parameters

\[
\text{RIM31} = 20\log_{10}(|\Gamma_{\text{out}}|) - G_A + \text{IM31},
\]

where \(20\log_{10}(|\Gamma_{\text{out}}|)\) is the active output reflection coefficient and \(G_A\) is the available gain. The relationship states that IM31 interacts with \(G_A\) in the same way as RIM31 interacts with \(20\log_{10}(|\Gamma_{\text{out}}|)\). The estimator error was measured to be approximately \(\pm 3.5\text{dB}\) over several frequency offsets, which is reasonable when relating behaviours \(30\text{dB}\) apart.

To demonstrate the general weakly-nonlinear similarity between both processes we consider the large-signal Angelov model [8], a representative model for multiple III-V device technologies, and are, in this context, only interested in its non-linear properties. We express the normalized drain current as

\[
I_{ds} = (1 + \tanh(V_{gs}))\tanh(\alpha V_{ds})(1 + \lambda V_{ds}),
\]

where \(V_{gs}\) is the gate-source voltage, \(V_{ds}\) is the drain-source voltage, \(\lambda\) is the channel length modulation parameter and \(\alpha\) is the saturation voltage parameter.

We first consider the IMD case, in which the stimulus becomes \(V_1 + V_2\), where \(V_i\) are two signals at different frequencies. In this configuration \(\tanh(\alpha V_{ds})(1 + \lambda V_{ds}) = A\) can be treated as a constant and thus, without loss of generality, we have

\[
I_{ds} \approx A(1 + \tanh(V_1 + V_2)) = A\frac{2e^{2(V_1 + V_2)}}{e^{2(V_1 + V_2)} + 1}.
\]

Next we consider the RIMD case, where the now reverse-injected signal, \(V_2\), propagates, due to the reciprocity of the output-matching network, towards the drain-terminal where it causes a variation on the drain-source voltage, \(V_{ds}\).
which influences $I_{ds}$. The result can be simplified by setting

$$1 + \lambda(V_{ds} + V_2) = B(V_2)$$

such that

$$I_{ds} \approx B(V_2) e^{2(V_1 + \alpha(V_a + V_2))} - 2e^{2V_1} \quad (4)$$

Equations 3 and 4 both have similar two-tone exponential terms that result in similar intermodulation products. The most observable difference between them is that (4) has additional single tone terms in both the numerator and denominator. This causes the generated RIMD terms from the output to be attenuated. This is to be expected, as the reverse power does not experience any gain when generating RIMD, while also being attenuated by the output reflection coefficient.

**B. Identification Methodology**

The RIMD estimator can be used to determine which stage enters compression first because it will agree with measurements, within some margin, only when the dominant compression occurs in the last stage of the PA. This is because if the IMD and RIMD products are created at the same stage, they can be related to one another via Eqn. (1).

If the dominant compression of the PA occurs at the first stage, the IMD products will increase substantially, due to $G_A$ of the whole PA, while the RIMD ones will not. The second stage will not be able to generate such strong intermodulation products by itself. This divergence between IMD and RIMD power levels serves as the indicator. The compression point of the first stage will limit the entire PA and the RIMD measurements will differ from the estimate by some amount, $\Delta_c$, which we define as

$$\Delta_c = |\text{RIM31} - \text{RIM31}|.$$  

(5)

The error is caused by the increased IMD products together with the available gain of the second stage only. If this gain is not known precisely then the magnitude provides no insight. If both stages are linear, then the IMD and RIMD products will require high dynamic range to measure accurately.

On the other hand, if both stages are driven in strong compression, the IMD components of the first stage will be indistinguishable from those generated by the second stage and $\Delta_c$ will be small, providing no insight. Thus, the PA must be driven such that it operates under-large signal conditions, but not in strong compression, similar to the P1dB compression point as is done with hot S-parameter measurements [9].

As such, the procedure involves first measuring the available gain, $G_A$, of the device. Next, while the device operates at its P1dB compression point, the IM31, RIM31 and $\Gamma_{out}$ are measured so that $\Delta_c$ can be computed.

**III. COMPRESSION STAGE IDENTIFICATION VERIFICATION**

To validate the utility of the RIMD estimator we use a set of different HBT [10]–[13] and one E-PHEMPT [14] single-stage PA to construct several two-stage device under test (DUT) combinations. The biasing of either stage is adjusted so as to change which stage of the DUT enters dominant compression, allowing us to emulate designs that are compressing in either the first or the second stage. The RIMD measurements are compared to the estimates and the magnitude of the error is used to identify the compressing stage.

**A. Measurement Setup**

The first step in identifying the DUT’s compression stage is characterizing $G_A$. The available gain is measured with a single tone input power sweep at the frequency of interest. The IMD behaviour of the DUT is measured with the setup shown in Figure 1a). A main tone, $P_1$, and a probe tone, $P_2$, are fed at the input of the DUT. The probe tone is chosen such that it is 10dB weaker than $P_1$, so that it does not influence the large-signal behaviour, in line with regular hot S-parameter measurements [7]. The lower $P_2$ is, the lower its influence will be on the DUT, however the lower IMD and RIMD products will require increased dynamic range from the measurement equipment. The main tone is set to the P0.1dB, P1dB and P3dB compression points of the DUT and is offset by frequency $\Delta_f$ of [1, 10, 100, 150]MHz from the probe tone. The frequency offsets are chosen such that they cover a representative range, while still close enough to have the same S-parameters. The strongest IMD product, IM31, is observed and recorded using a spectrum analyzer via a 20dB directional coupler.

Measurement of the RIMD behavior is done using the setup shown in Figure 1b). The $P_2$ probe tone is now fed at the output of the DUT and isolated through a circulator. First, the active $|\Gamma_{out}|^2$ is measured for the given $\Delta_f$ and compression point. Both tones, $P_1$ and $P_2$, have the same amplitudes as with the IMD measurement. The RIMD products, which are much weaker than their IMD counterparts, are also observed with the spectrum analyzer via the same coupler.

For accuracy concerns, special care was taken to have only a minimal amount of reconfiguration between IM31 and RIM31 measurements, such that only two devices needed to be swapped. The fact that no specialized hardware is required facilitates a wide adoption of the method.

**Fig. 1. RIMD and IMD measurement setups. In both cases the generator tones are kept the same.**
**B. Measurement Results**

Figure 2a) shows the output spectrum, after the 20dB coupler, of an IMD measurement of a DUT consisting of ZX60-V82-S+ (HBT) input stage and ZX60-P33ULN+ (E-PHEMPT) output stage. The DUT is biased such that the second stage creates dominant compression. The input powers are $P_1 = 2$dBm at 1.51GHz and $P_2 = -12$dBm at 1.50GHz ($\Delta_f = 10$MHz), and the output powers are 26.8dBm and 12.8dBm, respectively. The DUT operates at its $P_{1\text{dB}}$ compression point, with $G_A = 24.8$dB. The difference in input power levels results in the IM3 components having different magnitudes and slopes, the strongest one being IM31 at 1.52GHz with a slope of 1dB/db, while the second intermodulation component, IM32, is at 1.49GHz and has a slope of 2dB/db and is weaker in magnitude.

Figure 2b) shows the output spectrum of an RIMD measurement on the same DUT. Both $P_1$ and $P_2$ remain unchanged in power and frequency, but $P_2$ is applied to the output of the DUT. The measured output power is $P_{O1} = -3.2$dBm and $P_{O2} = -63.0$dBm, which tells us (Eqn. (1)) that the active $|\Gamma_{\text{out}}|^2 = -8.3$dB. As with the IMD measurement, the strongest reverse intermodulation component, RIM31, located at 1.52GHz, has a slope of 1dB/db, while the second reverse intermodulation component, RIM32, has a slope of 2dB/db.

The RIMD estimator is in good agreement with measurements, resulting in $\Delta_e = [34.3 - 36.4] = 2.1$dB. The rest of the frequency offsets yield 1.7dB at 1MHz, 3.0dB at 100MHz and 1.1dB at 150MHz, respectively. When the same DUT is biased such that the first stage enters compression first, and the IMD and RIMD measurements are repeated under the exact same conditions, the estimator error becomes 13.5dB. Figure 3 shows the new IMD and RIMD results. The other frequency offsets yield an estimator error of 14.8dB at 1MHz, 16.5dB at 100MHz and 16.5dB at 150MHz. Table 1 shows the RIMD estimator error, $\Delta_e$, for all $\Delta_f$ offsets for several DUT combinations which have been biased such that either the first stage or the second stage enter compression first. As pointed out earlier, the most consistent results are obtained when $P_1$ is set around the P1db compression point. Significantly lower values (e.g. P0.1dB) lead to measurement inaccuracies due to the low signal levels, significantly higher values (e.g. P3dB) removes the dominance of the nonlinearity, and hence obfuscates the results. Additionally, the most distinct performance is obtained when $\Delta_f = [1, 10]$MHz. At higher frequency offsets there seems to be no guarantee the device parameters will remain the same.

The method is able to identify the compressing stage most consistently at small $\Delta_f$, such as 1MHz and 10MHz, when the DUT operates around the P1dB compression point. At higher frequency offsets such as 100MHz and 150MHz the estimator cannot be trusted consistently. It can be concluded that when $\Delta_e < 4$dB the second stage enters compression first. When $\Delta_e > 8$dB, a significant difference, the first stage enters compression first, limiting the compression point of the entire system.

**IV. CONCLUSION**

In this work we have further explored the relationship between IMD and RIMD and applied the RIMD estimator proposed in [6] to identify which stage enters compression first in a two-stage PA device using only linear measurement equipment. To validate our assumptions we measured seven two-stage DUTs consisting of combinations E-PHEMPT and HBT-based single-stage PAs. The different technologies and topologies of each device support the general applicability of the estimator.

The DUT configurations were evaluated at several frequency offsets and compression points. At around the P1dB compression point and $\Delta_f = [1, 10]$MHz the estimator error, $\Delta_e$, is able to identify the compressing stage consistently. The well-designed DUT configurations resulted in $\Delta_e < 4$dB, while the DUTs which compressed at the first stage had $\Delta_e > 8$dB.
Fig. 3. IMD and RIMD spectra, via the 20dB coupler, of DUT consisting of ZX60-V82+ (HBT) input stage and ZX60-P33ULN+ (E-PHEMPT) output stage with $\Delta_f = 10$ MHz, $P_1 = 2$ dBm and $P_2 = -12$ dBm. The DUT compresses at the input stage.

**REFERENCES**


